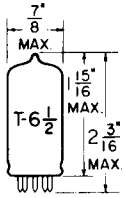
TUNG-SOL

DOUBLE TRIODE

MINIATURE TYPE

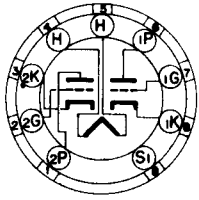


GLASS BULB

COATED UNIPOTENTIAL CATHODE

HEATER
4.2 VOLTS 0.6 AMP.
AC OR DC

ANY MOUNTING POSITION



BOTTOM VIEW
MINIATURE BUTTON
9 PIN NOVAL
9AJ

THE 4BQ7A, A MEDIUM-MU DOUBLE TRIODE USING THE 9 PIN MINIATURE CONSTRUCTION, IS DESIGNED FOR USE IN 600 MA. SERIES HEATER OPERATED RECEIVERS. IT IS INTENDED FOR SERVICE AS THE FIRST RF AMPLIFIER TUBE IN TUNERS OF VHF TELEVISION RECEIVERS OR AS A LOW NOISE IF PRE-AMPLIFIER TUBE IN UHF TELEVISION RECEIVERS EMPLOYING A CRYSTAL MIXER. HIGH TRANSCONDUCTANCE, LOW INPUT CAPACITANCE, LOW INPUT LOADING, AND LOW PLATE TO CATHODE CAPACITANCE MAKE IT SPECIALLY USEFUL IN THE DIRECT-COUPLED RF STAGE OF TELEVISION RECEIVERS UTILIZING A DRIVEN RF-GROUNDED-GRID AMPLIFIER FOR THE CASCODE TYPE OF CIRCUIT. THERMAL CHARACTERISTICS OF THE HEATER ARE CONTROLLED SUCH THAT HEATER VOLTAGE SURGES DURING THE WARM-UP CYCLE ARE MINIMIZED PROVIDED IT IS USED WITH OTHER TYPES THAT ARE SIMILARLY CONTROLLED. WITH THE EXCEPTION OF HEATER RATINGS, ITS CHARACTERISTICS ARE IDENTICAL TO THE 6BQ7A.

DIRECT INTERELECTRODE CAPACITANCES

WITH EXTERNAL SHIELD #315

	UNIT #1	UNIT #2	
GRID TO PLATE	1.15	1.15	μμf
INPUT	2.85	----	μμf
INPUT (GROUNDED GRID)	----	4.95	μμf
OUTPUT	1.35	----	μμf
OUTPUT (GROUNDED GRID)	----	2.27	μμf
PLATE TO CATHODE (MAX.)	0.15	0.15	μμf
HEATER TO CATHODE	2.65	2.70	μμf
PLATE OF UNIT #1 TO PLATE OF UNIT #2 (MAX.)	0.010		μμf
PLATE OF UNIT #2 TO PLATE AND GRID OF UNIT #1 (MAX.)	0.024		μμf

RATINGS

INTERPRETED ACCORDING TO DESIGN CENTER VALUES

CLASS A_1 AMPLIFIER - EACH TRIODE UNIT

HEATER VOLTAGE	4.2	VOLTS
→ MAXIMUM HEATER CATHODE VOLTAGE:		
HEATER NEGATIVE WITH RESPECT TO CATHODE		
TOTAL DC AND PEAK	200	VOLTS
HEATER POSITIVE WITH RESPECT TO CATHODE		
DC	100	VOLTS
TOTAL DC AND PEAK	200	VOLTS
MAXIMUM PLATE VOLTAGE	250[A]	VOLTS
MAXIMUM PLATE DISSIPATION	2	WATTS
MAXIMUM CATHODE CURRENT	20	MA.
MAXIMUM GRID CIRCUIT RESISTANCE	0.5	MEGOHM
HEATER WARM-UP TIME (APPROX.)*	11.0	SEC.

[A] UNDER CUT-OFF CONDITIONS, IN RF-GROUNDED-GRID CIRCUITS WITH DIRECT-COUPLED DRIVE, IT IS PERMISSIBLE FOR THIS VOLTAGE TO BE AS HIGH AS 300 VOLTS.

* HEATER WARM-UP TIME IS DEFINED AS THE TIME REQUIRED FOR THE VOLTAGE ACROSS THE HEATER TO REACH 80% OF ITS RATED VOLTAGE AFTER APPLYING 4 TIMES RATED HEATER VOLTAGE TO A CIRCUIT CONSISTING OF THE TUBE HEATER IN SERIES WITH A RESISTANCE OF VALUE 3 TIMES THE NOMINAL HEATER OPERATING RESISTANCE.

CONTINUED ON FOLLOWING PAGE

→ INDICATES A CHANGE.

TUNG-SOL

CONTINUED FROM PRECEDING PAGE

TYPICAL OPERATING CONDITIONS AND CHARACTERISTICS

CLASS A_1 AMPLIFIER – EACH UNIT

	DESIGN CENTER VALUES	
HEATER VOLTAGE	4.2	VOLTS
HEATER CURRENT	0.6	AMP.
PLATE VOLTAGE	150	VOLTS
CATHODE BIAS RESISTOR	220	OHMS
AMPLIFICATION FACTOR	39	
PLATE RESISTANCE	6 100	OHMS
TRANSCONDUCTANCE	6 400	µMHOS
PLATE CURRENT	9	MA.
GRID VOLTS (APPROX.) FOR I_b = 10 µAMP.	−10	VOLTS

PUSH–PULL RF GROUNDED GRID CIRCUIT – EACH UNIT

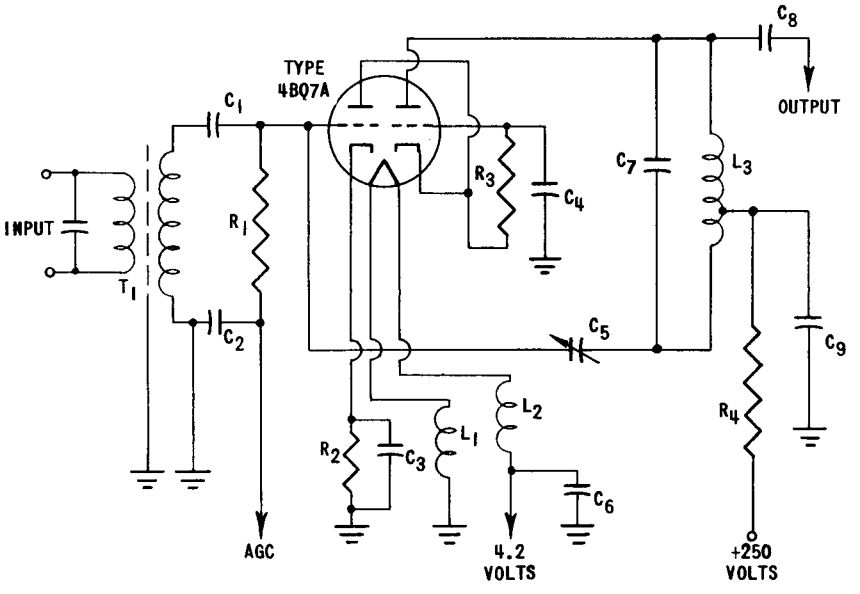
HEATER VOLTAGE	4.2	VOLTS
HEATER CURRENT	0.6	AMP.
PLATE VOLTAGE	150	VOLTS
GRID VOLTAGE (OBTAINED FROM CATHODE RESISTOR)	−2	VOLTS
CATHODE RESISTOR (COMMON TO BOTH UNITS)	100	OHMS
PLATE CURRENT	10	MA.

RF GROUNDED GRID CIRCUIT WITH DIRECT–COUPLED DRIVE

UNIT #1 (DRIVER TUBE) IS DIRECTLY COUPLED TO UNIT #2 (DRIVEN RF–GROUNDED–GRID AMPLIFIER TUBE) AS SHOWN IN ACCOMPANYING CIRCUIT.

	UNIT #1	UNIT #2	
HEATER VOLTAGE	4.2	4.2	VOLTS
HEATER CURRENT	0.6	0.6	AMP.
PEAK HEATER CATHODE VOLTAGE: HEATER NEGATIVE WITH RESPECT TO CATHODE	1	250	VOLTS
PLATE SUPPLY VOLTAGE	250	250	VOLTS
PLATE VOLTAGE	135	115	VOLTS
GRID VOLTAGE	−1	---	VOLTS
GRID RESISTOR	---	0.5	MEGOHM
PLATE CURRENT	10	10	MA.
GRID CURRENT	0	0	MA.
GRID VOLTAGE (APPROX.) FOR I_b = 10 µAMP.	−14	---	VOLTS

TUNG-SOL

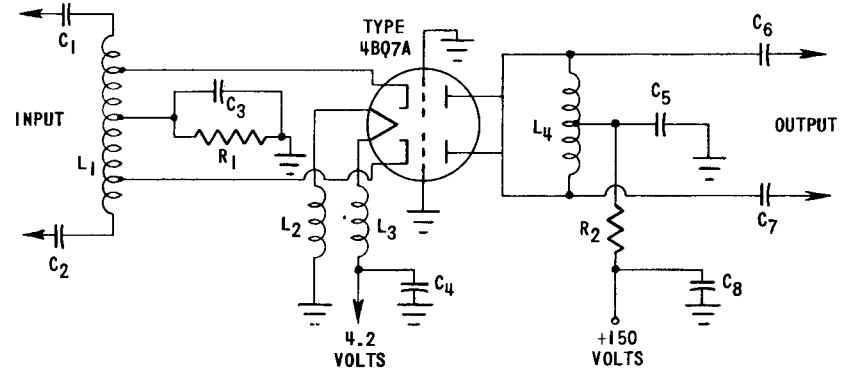


C1: 33 uuf, 400 VOLTS
C2: 1000 uuf, 400 VOLTS
C3: 1000 uuf, 400 VOLTS
C4: 1000 uuf, 400 VOLTS
C5: 0.5 to 1.5 uuf, 400 VOLTS
C6: 1000 uuf, 400 VOLTS
C7: 2 uuf, 400 VOLTS
C8: 33 uuf, 400 VOLTS
C9: 1000 uuf, 400 VOLTS

L1, L2: BIFILAR CHOKES, EACH 10 TURNS NO. 18 ENAMEL WIRE 1/4" COIL FORM
L3: TUNED CIRCUIT ELEMENT OF TUNER. VALUE DEPENDS ON DISTRIBUTED CIRCUIT CAPACITANCES. TO DETERMINE TAP POINT, TAP DOWN TO 80 TO 90% OF TOTAL NUMBER OF TURNS

R1: 10000 OHMS, 0.5 WATT
R2: 100 OHMS, 0.5 WATT
R3: 500000 OHMS, 0.5 WATT
R4: 100 OHMS, 0.5 WATT
T1: TUNED CIRCUIT ELEMENT OF TUNER. VALUE DEPENDS ON DISTRIBUTED CIRCUIT CAPACITANCES.

DRIVEN RF-GROUNDED GRID AMPLIFIER CIRCUIT WITH DIRECT COUPLED DRIVE



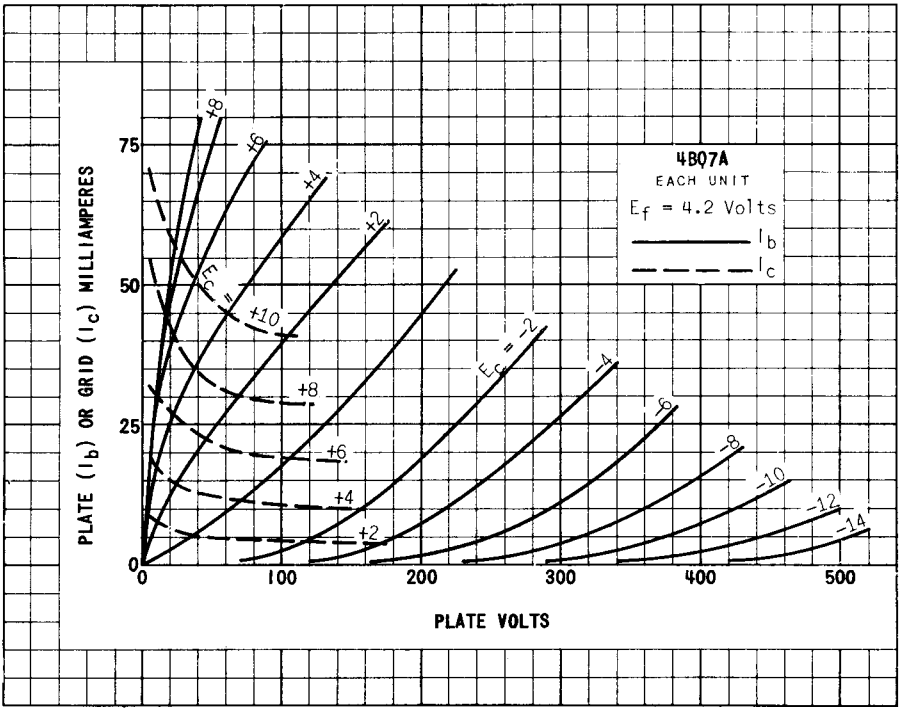
C1 C2 C3 C4 C5: 1000 uuf, 400 VOLTS
C6 C7: 100 uuf, 400 VOLTS
C8: 1000 uuf, 400 VOLTS

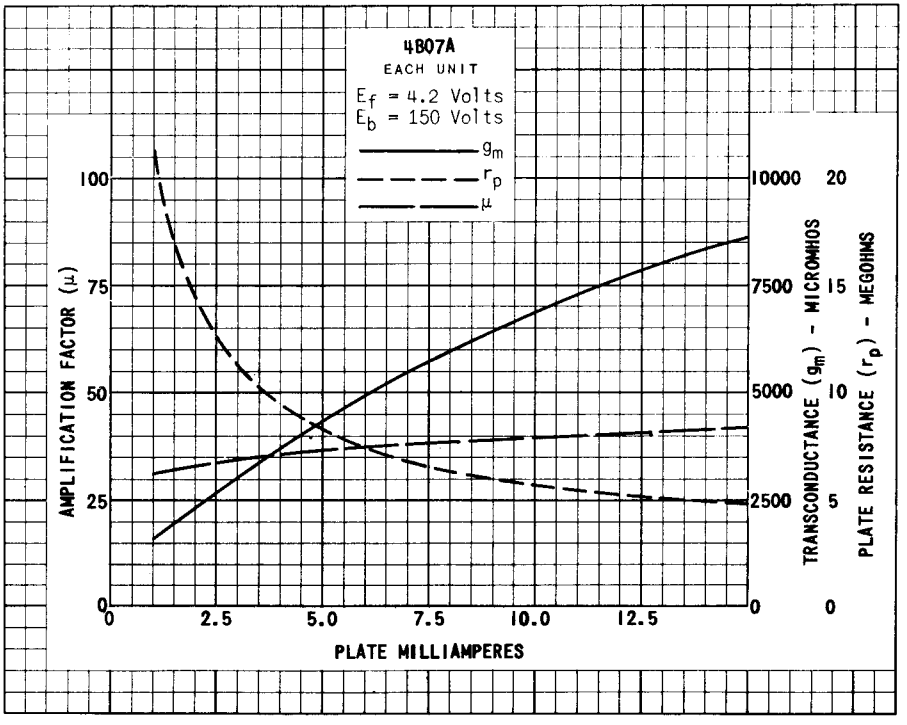
L1 L4: TUNED CIRCUIT ELEMENTS OF TUNER. VALUES DEPEND ON DISTRIBUTED CIRCUIT CAPACITANCES.

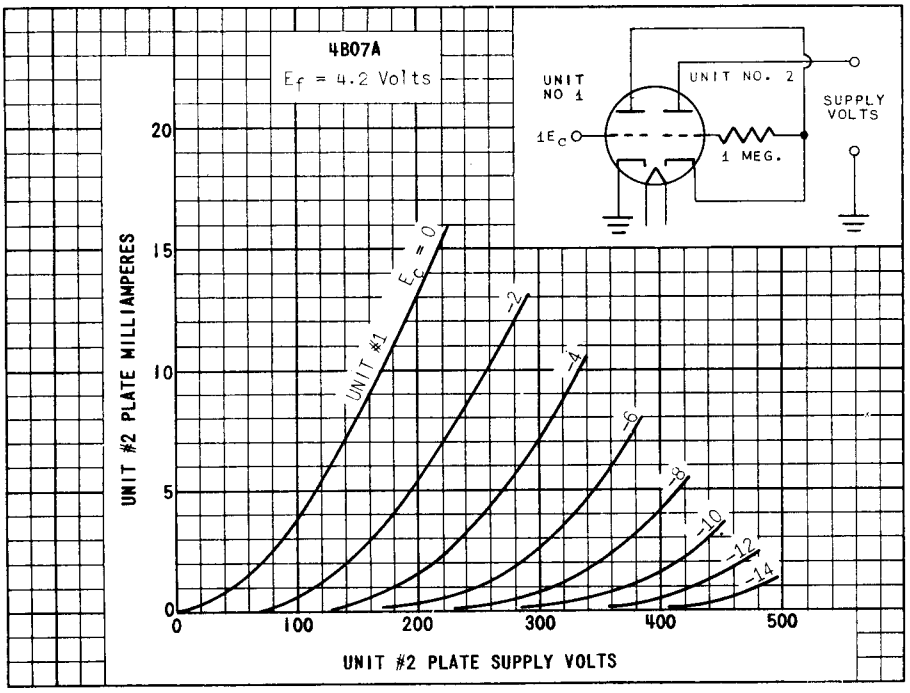
L2 L3: BIFILAR CHOKES, EACH 10 TURNS OF NO. 18 ENAMEL WIRE, 1/4" COIL FORM.
R1 R2: 100 OHMS, 0.5 WATT

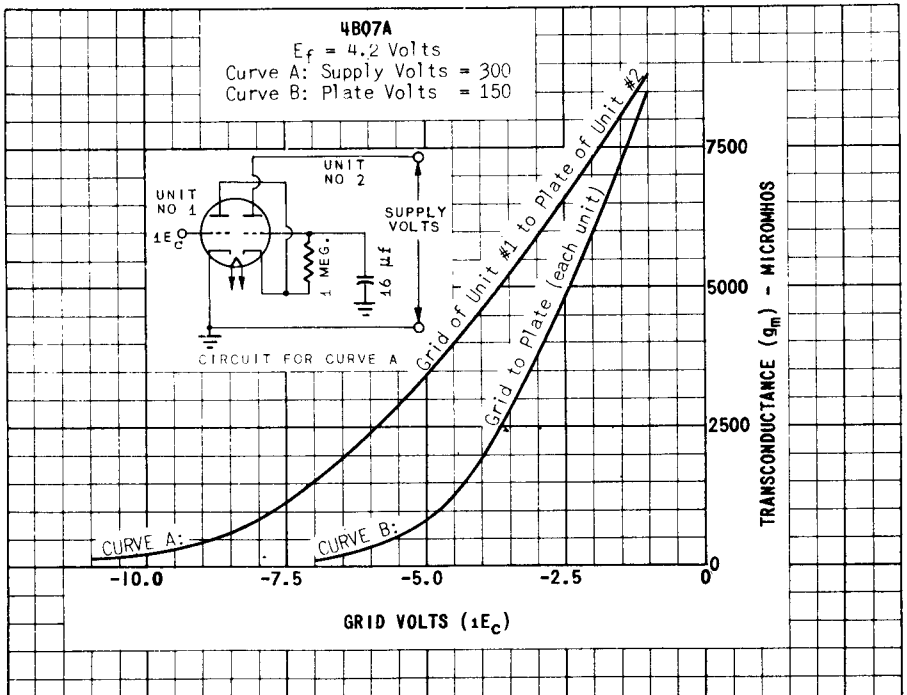
PUSH-PULL RF GROUNDED-GRID CIRCUIT

4BQ7A


4BQ7A
EACH UNIT
E_f = 4.2 Volts
I_b
I_c
PLATE (I_b) OR GRID (I_c) MILLIAMPERES
PLATE VOLTS
E_c = +8
+6
+4
+2
0
+10
-2
-4
-6
-8
-10
-12
-14
0
25
50
75
100
200
300
400
500


4BQ7A
EACH UNIT
E_f = 4.2 Volts
E_b = 150 Volts
g_m
r_p
μ
AMPLIFICATION FACTOR (μ)
TRANSCONDUCTANCE (g_m) - MICROMHOS
PLATE RESISTANCE (r_p) - MEGOHMS
PLATE MILLIAMPERES
0
25
50
75
100
2.5
5.0
7.5
10.0
12.5
2500
5000
7500
10000
5
10
15
20





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